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Evaluation of Microplasma Discharges as Active Components for Reconfigurable Antennas

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Abstract—This paper presents an experimental setup for the wideband RF characterization of plasma Micro Hollow Cathode Sustained Discharge (MHCD). This microdischarge is studied as a candidate for integrated active component in antennas, using the change of permittivity caused by the presence of plasma. The measurement setup consists of a 50 Ω microstrip line with a single MHCD placed in its center. The measurement of the scattering parameters of the experimental device permits the evaluation of the complex permittivity and conductivity of the MHCD.

I. INTRODUCTION

Due to their physical characteristics, plasma discharges appear as interesting candidates in the research of new devices in the RF domain. A plasma medium is an ionized gas, with the particularity that it can behave as a low permittivity material or as a conductor with low conductivity at several frequencies, and under certain conditions. On the other hand, when the gas is not ionized (so the discharge is not present), the medium remains electromagnetically transparent, like vacuum. In fact, the complex permittivity of the plasma medium depends on the plasma density and collision frequency, which depend on the type of gas, its pressure and the power injected to the discharge.

The use of plasma discharges on the RF domain has been case of several studies. One example is the plasma filled tubes used as radiating elements [1], [2]. Good results in this topic have been obtained for a wide frequency range (500 MHz to 20 GHz) with efficiencies comparable to classic copperwire antennas [3]. Other devices such as RADAR Transmit-Receiver tubes use also high power plasma discharges for their operation [4].

The possible control of the complex permittivity of the plasma discharge makes it interesting for RF components reconfiguration [5], [6]. Under this perspective, the Micro Hollow Cathode Sustained Discharge (MHCD) seems to be a good candidate for a possible integration in a RF printed circuit due to its small size (around 1 mm) [7].

Before using the MHCD in a RF circuit, it is necessary to characterize its complex permittivity behavior. A measuring device consisting of a 50 Ω microstrip line with a single MHCD placed in its center is proposed. This device permits the wideband evaluation (1 to 15 GHz) of the S parameters of the MHCD as a function of several parameters (gas pressure, electric current and applied voltage).

II. PLASMA DISCHARGE

A. Plasma characteristics

A plasma is an ionized gas, macroscopically neutral, with the characteristic of being a conducting medium. One way to create a plasma at ambient temperature is by applying an electromagnetic field to a gas. This will cause an acceleration of the free electrons present in the gas, providing the enough kinetic energy to produce collisions and so, ionize other molecules. This phenomenon, called avalanche breakdown, leads to the generation of an electric discharge and therefore, the formation of the plasma media.

One parameter that defines the type of plasma discharge is the ionization degree δ defined as:

$$\delta = \frac{n_e}{n_e + n_0} \tag{1}$$

where n_e is the electron density and n_0 is the neutral density. The MHCD device creates plasmas with low ionization degree, typically $\delta \leq 10^{-3}$, that are called non-equilibrium plasmas. Thus, this kind of plasmas allows heavy particles to keep their temperature close to room temperature whereas electron are warmed enough to ionize.

According to the Drude's model, the complex permittivity ϵ of the plasma and so, the complex conductivity σ can be defined as:

$$\epsilon = 1 - \frac{\omega_p^2}{\omega^2 - j\nu_p \cdot \omega} \tag{2}$$

$$\sigma = \frac{\omega_p^2 \cdot \epsilon_0}{\nu_p^2 + \omega^2} \cdot (\nu_p - j\omega) \tag{3}$$

where ω (rad/s) is the RF pulsation of the electromagnetic wave interacting with the plasma, ν_p the collision frequency (s⁻¹) and ω_p the plasma pulsation (rad/s) defined as:

$$\omega_p = \sqrt{\frac{n_e \cdot q^2}{\epsilon_0 \cdot m_e}} \tag{4}$$

where n_e is the electron density, q the electron charge and m_e the electron mass.

As exposed in (2) and (3), the complex permittivity and conductivity of the plasma depend on the collision frequency and the electron density (both dependent on the type of gas, the

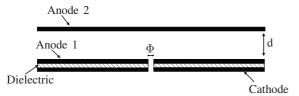


Fig. 1: Micro Hollow Cathode Sustained Discharge (MHCD) configuration.

gas pressure and the power injected to the discharge). Therefore, it is possible to control the electromagnetic behavior of the plasma medium, and modify the way it interacts with an incident RF electromagnetic wave.

B. Micro Hollow Cathode Sustained Discharge

Among the structures that enable the generation of non-equilibrium, the MHCD has several interesting characteristics for a possible integration in a RF planar circuit, such as its small size and the possibility to generate very localized discharges.

As shown in Fig. 1, the MHCD is a three electrode configuration discharge. On the first section of the device a very thin substrate (several hundred micrometers) is placed between two planar electrodes (Cathode and $Anode\ I$), where a central cylindrical hole of diameter Φ is drilled between these three layers. The function of the dielectric layer is to electrically isolate these two electrodes. When a DC voltage is applied (several hundreds volts) between these two electrodes, a plasma discharge takes place inside the hole. Finally, a third electrode ($Anode\ 2$) is placed at a distance d (up to several millimeters) from the $Anode\ I$. This electrode, when positively DC biased, pulls up the discharge and creates a larger volume plasma between the $Anode\ I$ and the $Anode\ 2$ [8].

In order to characterize the interaction between a RF electromagnetic wave and the plasma discharge generated between the *Anode 1* and the *Anode 2*, a measurement device that includes a MHCD has been designed.

III. MEASUREMENT DEVICE

A 3D representation of the device is exposed in Fig. 2. The measurement device consists of a 50 Ω microstrip line with a hole in its center where the plasma discharge takes place. Its objective is to measure the influence of the plasma discharge on the S parameters of the microstrip transmission line. The device configuration is exposed in Fig. 3. All the electrodes are made of copper, the microstrip line is made of gold and the dielectrics are made of alumina due to the high temperatures expected in the discharge area (around 900 K).

In addition to the three electrodes used for the MHCD generation, a RF section is placed on top of $Anode\ 1$ to characterize the discharge. It consists of a microstrip line etched on an alumina substrate with a hole of a diameter Φ at its center (Fig. 4). This hole is aligned with the hole of the MHCD configuration. Note that $Anode\ 1$ is also used as the RF ground plane for the transmission line, and also,

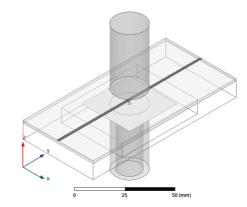


Fig. 2: 3D view of the characterization device

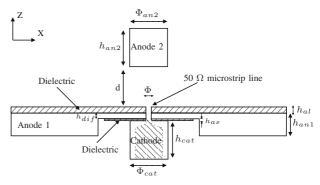


Fig. 3: Cut view of the measuring device.

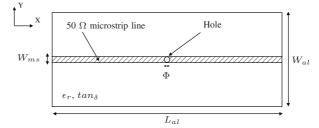


Fig. 4: Top view of the RF section.

that this configuration permits a separation of the DC and RF excitations. Finally, when the discharge is pulled up by the *Anode 2*, it fills the hole placed under the microstrip line, and the plasma interacts with the RF electromagnetic field propagating along the microstrip line. This interaction can be evaluated by measuring the S parameters of the transmission line.

The final values of the device parameters are: $\Phi_{cat}=20~mm$; $h_{cat}=5~cm$; $h_{an1}=11~mm$; $h_{diff}=1~mm$; $h_{as}=600~\mu m$; $L_{al}=10~cm$; $W_{al}=5~cm$; $h_{al}=1,57~mm$; $W_{ms}=1,516~mm$; $\Phi=1~mm$; d=7~mm ; $\epsilon_r=9,9$; $tan\delta=2.10^{-4},~\phi_{an2}=20~mm$; $h_{an2}=5~cm$.

The measuring device is finally inserted in a vacuum chamber, where the type of gas (argon, helium) and its pressure can be controlled.

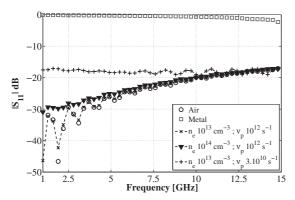


Fig. 5: Simulated reflection coefficient for different microdischarges

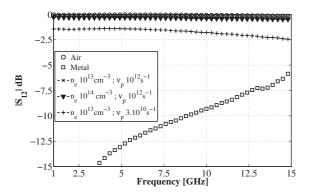


Fig. 6: Simulated transmission coefficient for different microdischarges

IV. RESULTS

Several simulations (using Ansoft HFSS [9]) were done to study the influence of the plasma parameters ω_p and ν_p on the S parameters of the line (Fig. 5 and Fig. 6).

Three different discharges were simulated considering expected values for ω_p and ν_p [10]. It concerns two atmospheric pressure ($\nu_p=1.10^{12}~s^{-1}$) discharges with electron densities of $10^{13}~cm^{-3}$ and $10^{14}~cm^{-3}~(\omega_p=1,8.10^{11}~rad/s$ and $5,6.10^{11}~rad/s$ respectively) and a low pressure discharge ($\nu_p=1.10^{10}~s^{-1}$) with an electron density of $10^{13}~cm^{-3}$. These discharges are compared with two reference cases: a metallic filled hole and an air filled hole.

As shown in Fig.5 and Fig.6, the behavior of the discharge depends on the ω_p/ν_p ratio. The results obtained with the atmospheric pressure discharges are similar to the ones obtained with the air filled hole case. This occurs because of the low conductivity and low relative permittivity values of the plasma ($\epsilon_r \approx 1$). For the low pressure discharge, the ω_p/ν_p ratio value increases and the S parameters are more influenced by the discharge. This behavior could be interesting for further studies targeting its use in RF components.

V. CONCLUSION

A wideband RF measurement device for the characterization of a plasma MHCD has been presented. The device offers a large possibility in terms of the control of plasma parameters (gas pressure, injected power, type of gas), that makes it interesting for the characterization of the discharge.

Simulations show significant changes on the S parameters depending on the ω_p/ν_p ratio. The device permits to explore the influence of different parameters of the discharge in order to obtain a suitable value of the ω_p/ν_p ratio for RF applications.

In future works, several measurements varying the discharge parameters will be carried out and compared with simulations in order to validate the obtained results.

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